

NAiS

**High capacity PhotoMOS Relay. (Load current Max. 4A)
DC load type is available.**

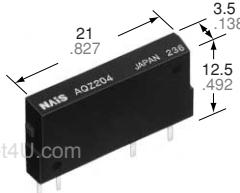
**Power PhotoMOS
(AQZ10○, 20○)**

FEATURES

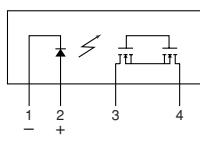
1. High capacity PhotoMOS Relay in a compact and slim 4-pin SIL
2. Extremely low ON resistance
3. Control low-level signal
Power Photo MOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
4. Low-level off state leakage current
5. High I/O isolation voltage 2,500 V
6. Eliminates the need for a counter electromotive protection diode in the drive circuit on the input side
7. Eliminate the need for a power supply to drive the power MOSFET
8. PC board layout is simplified
9. No restriction on mounting direction
10. Varistor incorporated type is also available.

TYPICAL APPLICATIONS

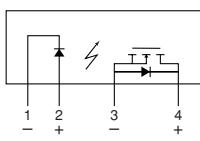
- High-speed inspection machines
- IC checker
- NC machine, Robots
- Office machines
- Telecommunication
- Automotive
- Industrial control



mm inch



AC/DC type



DC type

TYPES

1. AC/DC type

Output rating		Part No.	Packing quantity	
Load voltage	Load current		Inner carton	Outer carton
60 V	3.0 A	AQZ202	25 pcs.	500 pcs.
100 V	2.0 A			
200 V	1.0 A			
400 V	0.5 A			

2. DC type

Output rating		Part No.	Packing quantity	
Load voltage	Load current		Inner carton	Outer carton
60 V	4.0 A	AQZ102	25 pcs.	500 pcs.
100 V	2.6 A			
200 V	1.3 A			
400 V	0.7 A			

Notes: Load voltage and current of AC/DC type: Peak AC/DC.

Load voltage and current of DC type: DC

RATING**1. AC/DC type**

1) Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQZ202	AQZ205	AQZ207	AQZ204	Remarks
Input	LED forward current	I _F	50 mA				
	LED reverse voltage	V _R	5 V				
	Peak forward current	I _{FP}	1 A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW				
Output	Load voltage (Peak AC)	V _L	60 V	100 V	200 V	400 V	
	Continuous load current	I _L	3.0 A	2.0 A	1.0 A	0.5 A	
	Peak load current	I _{peak}	9.0 A	6.0 A	3.0 A	1.5 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	1.6 W				
Total power dissipation		P _T	1.6 W				
I/O isolation voltage		V _{iso}	2,500 V AC				
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures		
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F				

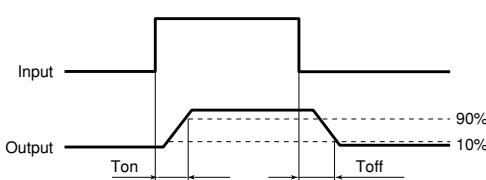
2) Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQZ202	AQZ205	AQZ207	AQZ204	Condition
Input	LED operate current	I _{Fon}	1.0 mA				I _L = 100 mA V _L = 10 V
			3.0 mA				
	LED turn off current	I _{Foff}	0.4 mA				I _L = 100 mA V _L = 10 V
			0.9 mA				
Output	LED dropout voltage	V _F	1.25 V (1.16 V at I _F = 10 mA)				I _F = 50 mA
			1.5 V				
	On resistance	R _{on}	0.11 Ω	0.23 Ω	0.7 Ω	2.1 Ω	I _F = 10 mA I _L = Max. Within 1 s on time
			0.18 Ω	0.34 Ω	1.1 Ω	3.2 Ω	
Transfer characteristics	Off state leakage current	Maximum	—	10 μA		I _F = 0 mA V _L = Max.	
	Switching speed	T _{on}	2.46 ms	2.40 ms	1.12 ms	1.65 ms	I _F = 10 mA I _L = 100 mA V _L = 10 V
			5.0 ms				
			5.64 ms	5.65 ms	2.57 ms	3.88 ms	I _F = 5 mA I _L = 100 mA V _L = 10 V
		T _{off}	10.0 ms				
			0.22 ms	0.21 ms	0.10 ms	0.08 ms	I _F = 5 mA or 10 mA I _L = 100 mA V _L = 10 V
	I/O capacitance	C _{iso}	0.8 pF				f = 1 MHz V _B = 0 V
			1.5 pF				
	Initial I/O isolation resistance	Minimum	R _{iso}	1,000 MΩ		500 V DC	
	Maximum operating speed	Maximum	—	0.5 cps		I _F = 10 mA Duty factor = 50% I _L = Max., V _L = Max.	
Vibration resistance		Minimum	—	10 to 55 Hz at double amplitude of 3 mm		2 hours for 3 axes	
Shock resistance		Minimum	—	4,900 m/s ² {500 G}1 ms		3 times for 3 axes	

Note: Recommendable LED forward current I_F = 5 to 10 mA.

For type of connection, see page 37.

*Turn on/off time



Power PhotoMOS (AQZ10○, 20○)

2. DC type

1) Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQZ102	AQZ105	AQZ107	AQZ104	Remarks
Input	LED forward current	I_F	50 mA				
	LED reverse voltage	V_R	5 V				
	Peak forward current	I_{FP}	1 A		$f = 100 \text{ Hz, Duty factor} = 0.1\%$		
	Power dissipation	P_{in}	75 mW				
Output	Load voltage (DC)	V_L	60 V	100 V	200 V	400 V	
	Continuous load current (DC)	I_L	4.0 A	2.6 A	1.3 A	0.7 A	
	Peak load current	I_{peak}	9.0 A	6.0 A	3.0 A	1.5 A	100 ms (1 shot), $V_L = \text{DC}$
	Power dissipation	P_{out}	1.35 W				
Total power dissipation		P_T	1.35 W				
I/O isolation voltage		V_{iso}	2,500 V AC				
Temperature limits	Operating	T_{opr}	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures		
	Storage	T_{stg}	-40°C to +100°C -40°F to +212°F				

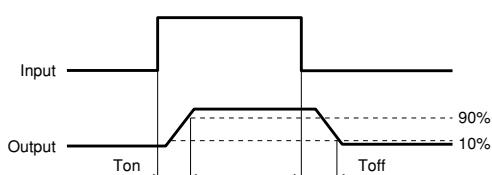
2) Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQZ102	AQZ105	AQZ107	AQZ104	Condition	
Input	LED operate current	I_{Fon}	1.0 mA		$I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$			
			3.0 mA					
	LED turn off current	I_{Foff}	0.4 mA		$I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$			
			0.9 mA					
Output	LED dropout voltage	V_F	1.25 V (1.16 V at $I_F = 10 \text{ mA}$)		$I_F = 50 \text{ mA}$			
			1.5 V					
	On resistance	R_{on}	0.05 Ω	0.081 Ω	0.34 Ω	1.06 Ω	$I_F = 10 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time	
			0.09 Ω	0.17 Ω	0.55 Ω	1.6 Ω		
Transfer characteristics	Off state leakage current	Maximum	—	10 μA		$I_F = 0 \text{ mA}$ $V_L = \text{Max.}$		
	Switching speed	Turn on time*	T_{on}	1.66 ms	1.89 ms	0.83 ms	1.01 ms	$I_F = 10 \text{ mA}$ $I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
				5.0 ms				
			T_{off}	3.79 ms	4.50 ms	1.75 ms	2.34 ms	$I_F = 5 \text{ mA}$ $I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
				10.0 ms				
	Turn off time*	Typical	C_{iso}	0.15 ms	0.19 ms	0.08 ms	0.08 ms	$I_F = 5 \text{ mA or } 10 \text{ mA}$ $I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
				3.0 ms				
	I/O capacitance	Typical	R_{iso}	0.8 pF		$f = 1 \text{ MHz}$ $V_B = 0 \text{ V}$		
	Initial I/O isolation resistance	Minimum		1.5 pF				
	Maximum operating speed	Maximum	—	1,000 MΩ		500 V DC		
Vibration resistance		Minimum	—	10 to 55 Hz at double amplitude of 3 mm		2 hours for 3 axes		
Shock resistance		Minimum	—	4,900 m/s² {500 G} 1 ms		3 times for 3 axes		

Note: Recommendable LED forward current $I_F = 5$ to 10 mA.

For type of connection, see page 37.

*Turn on/off time

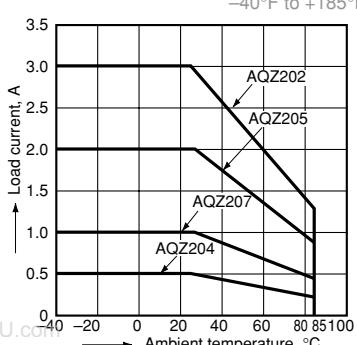


- For Dimensions, see Page 31.
- For Schematic and Wiring Diagrams, see Page 37.
- For Cautions for Use, see Page 42.

REFERENCE DATA

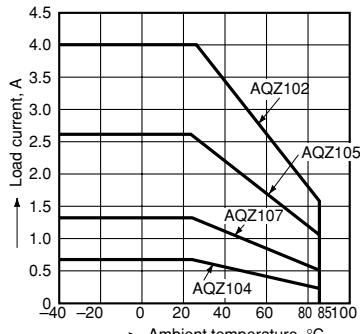
1.-(1) Load current vs. ambient temperature characteristics (AC/DC type)

Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$



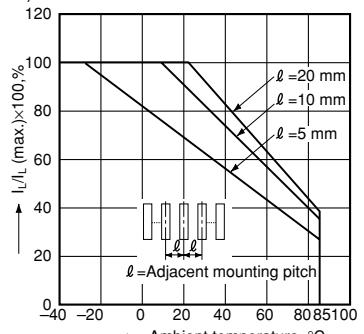
1.-(2) Load current vs. ambient temperature characteristics (DC type)

Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$



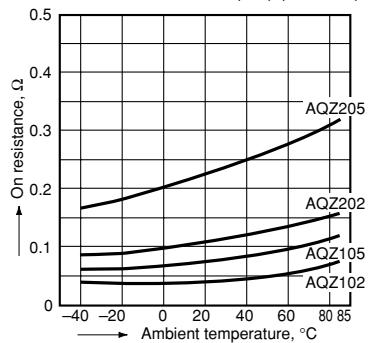
2. Load current vs. ambient temperature characteristics in adjacent mounting

I_L : Load current;
 $I_L(\text{max.})$: Maximum continuous load current



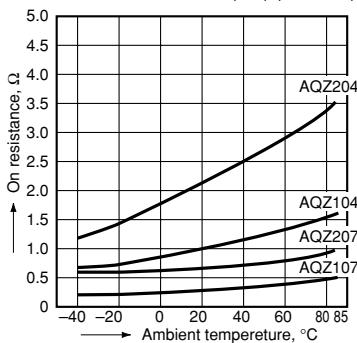
3.-(1) On resistance vs. ambient temperature characteristics

LED current: 10 mA;
Continuous load current: 1.2 A (DC) (AQZ202),
0.8 A (DC) (AQZ205),
1.6 A (DC) (AQZ102),
1.04 A (DC) (AQZ105)



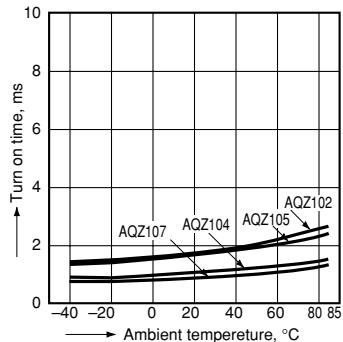
3.-(2) On resistance vs. ambient temperature characteristics

LED current: 10 mA;
Continuous load current: 0.4 A (DC) (AQZ207),
0.2 A (DC) (AQZ204),
0.52 A (DC) (AQZ107),
0.28 A (DC) (AQZ104)



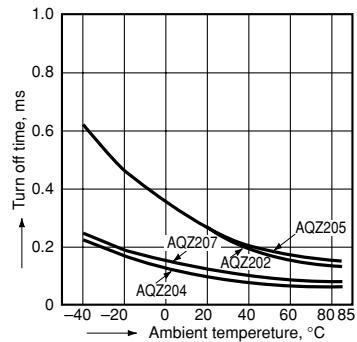
4.-(2) Turn on time vs. ambient temperature characteristics (DC type)

LED current: 10 mA;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



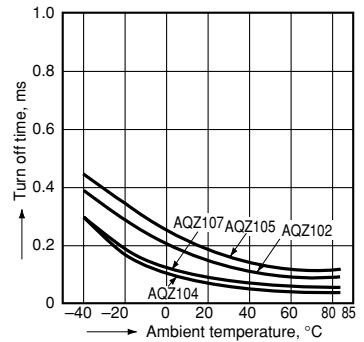
5.-(1) Turn off time vs. ambient temperature characteristics (AC/DC type)

LED current: 10 mA;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



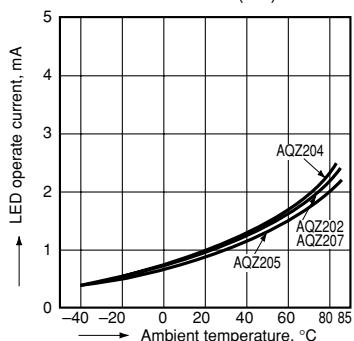
5.-(2) Turn off time vs. ambient temperature characteristics (DC type)

LED current: 10 mA;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



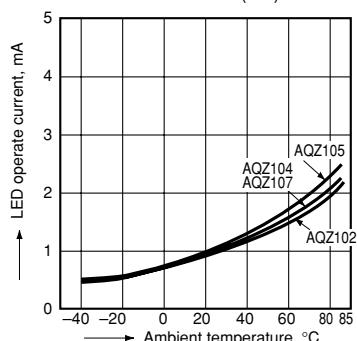
6.-(1) LED operate vs. ambient temperature characteristics (AC/DC type)

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



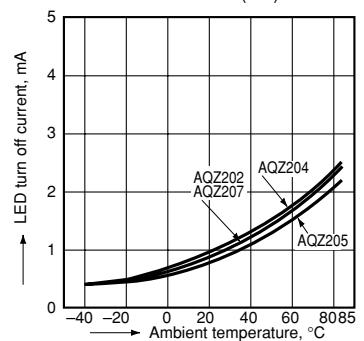
6.-(2) LED operate vs. ambient temperature characteristics (DC type)

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



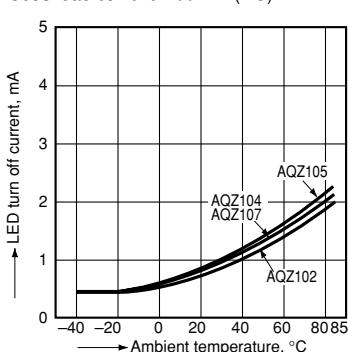
7.-(1) LED turn off current vs. ambient temperature characteristics (AC/DC type)

Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)

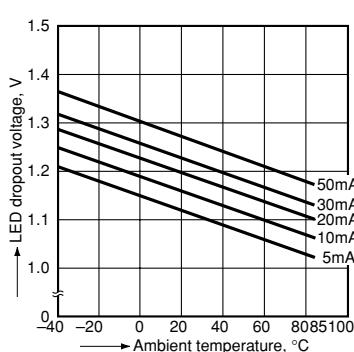


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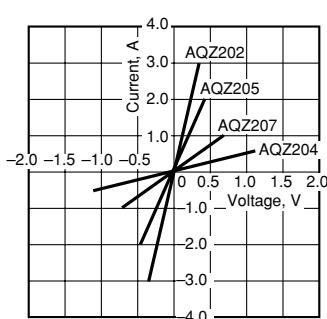
7.-(2) LED turn off current vs. ambient temperature characteristics (DC type)
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC)



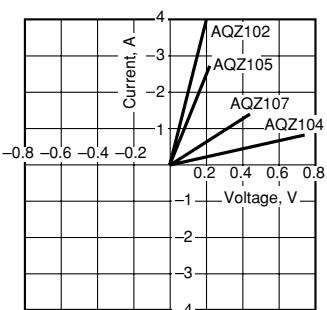
8. LED dropout voltage vs. ambient temperature characteristics
Sample: all types; LED current: 5 to 50 mA



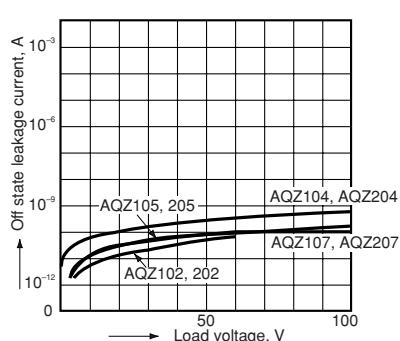
9.-(1) Current vs. voltage characteristics of output at MOS portion (AC/DC type)
Ambient temperature: 25°C 77°F



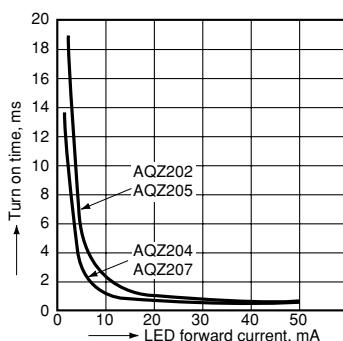
9.-(2) Current vs. voltage characteristics of output at MOS portion (DC type)
Ambient temperature: 25°C 77°F



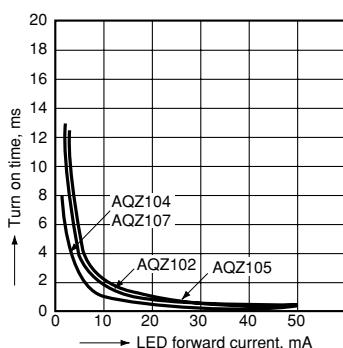
10. Off state leakage current vs. load voltage characteristics
Ambient temperature: 25°C 77°F



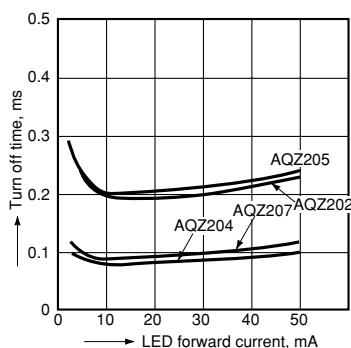
11.-(1) Turn on time vs. LED forward current characteristics (AC/DC type)
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



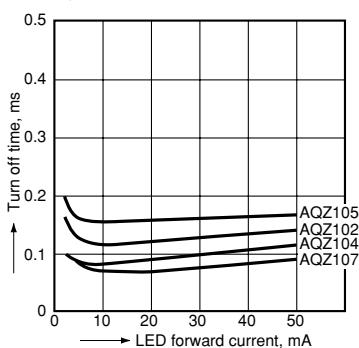
11.-(2) Turn on time vs. LED forward current characteristics (DC type)
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



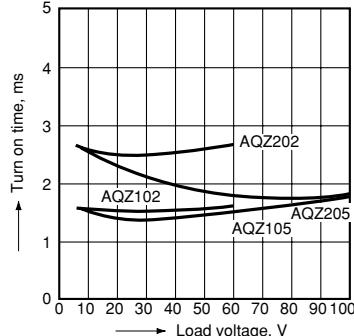
12.-(1) Turn off time vs. LED forward current characteristics (AC/DC type)
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



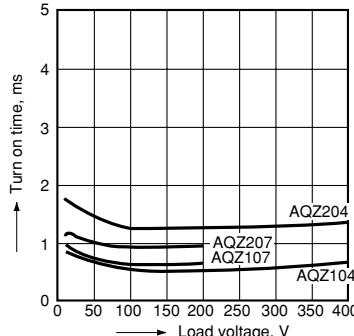
12.-(2) Turn off time vs. LED forward current characteristics (DC type)
Measured portion: between terminals 4 and 6;
Load voltage: 10 V (DC);
Continuous load current: 100 mA (DC);
Ambient temperature: 25°C 77°F



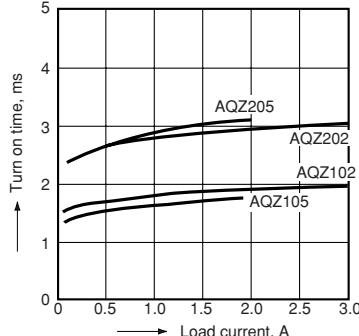
13.-(1) Turn on time vs. load voltage characteristics (Load voltage: 60, 100 V type)
LED current: 10 mA;
Continuous load current: 100 mA;
Ambient temperature: 25°C 77°F



13.-(2) Turn on time vs. load voltage characteristics (Load voltage: 200, 400 V type)
LED current: 10 mA;
Continuous load current: 100 mA;
Ambient temperature: 25°C 77°F

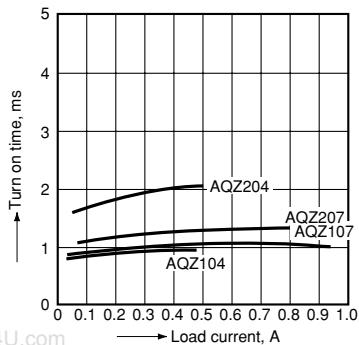


14.-(1) Turn on time vs. load current characteristics (Load voltage: 60, 100 V type)
LED current: 10 mA;
Load voltage: 10 V (DC);
Ambient temperature: 25°C 77°F

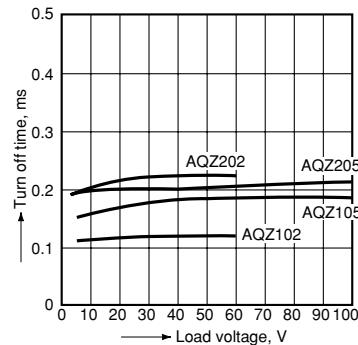


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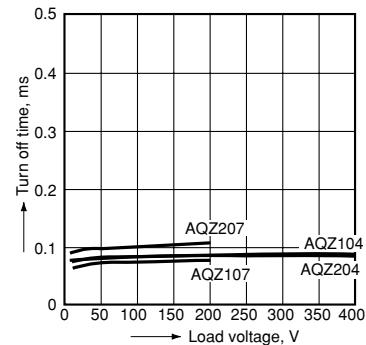
14.- (2) Turn on time vs. load current characteristics (Load voltage: 200, 400 V type)
 LED current: 10 mA;
 Load voltage: 10 V (DC);
 Ambient temperature: 25°C 77°F



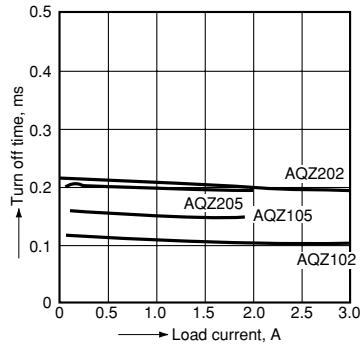
15.- (1) Turn off time vs. load voltage characteristics (Load voltage: 60, 100 V type)
 LED current: 10 mA;
 Continuous load current: 100 mA;
 Ambient temperature: 25°C 77°F



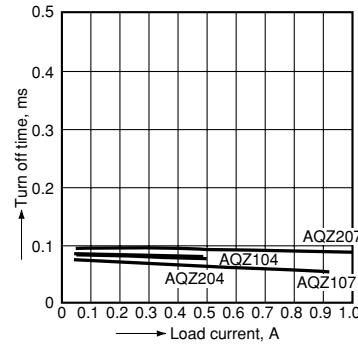
15.- (2) Turn off time vs. load voltage characteristics (Load voltage: 200, 400 V type)
 LED current: 10 mA;
 Continuous load current: 100 mA;
 Ambient temperature: 25°C 77°F



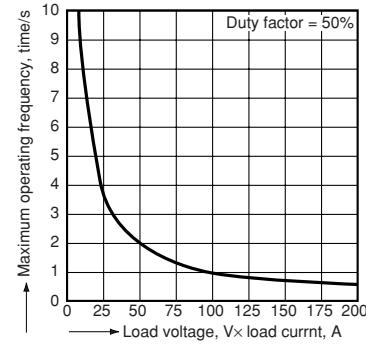
16.- (1) Turn off time vs. load current characteristics (Load voltage: 60, 100 V type)
 LED current: 10 mA;
 Load voltage: 10 V (DC);
 Ambient temperature: 25°C 77°F



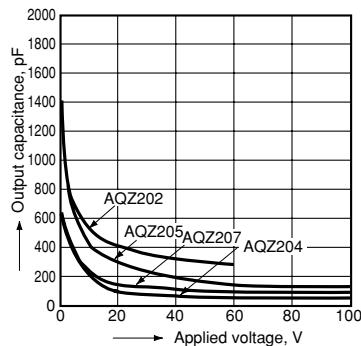
16.- (2) Turn off time vs. load current characteristics (Load voltage: 200, 400 V type)
 LED current: 10 mA;
 Load voltage: 10 V (DC);
 Ambient temperature: 25°C 77°F



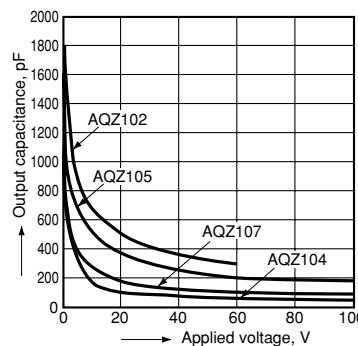
17. Maximum operating frequency vs. load voltage/current characteristics
 LED current: 10 mA;
 Ambient temperature: 25°C 77°F



18.- (1) Output capacitance vs. applied voltage characteristics (AC/DC type)
 Frequency: 1 MHz;
 Ambient temperature: 25°C 77°F

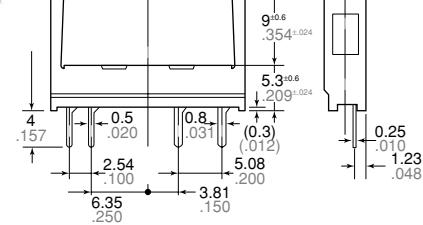
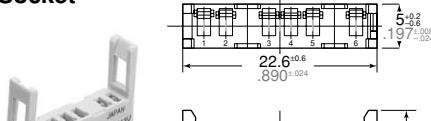


18.- (2) Output capacitance vs. applied voltage characteristics (DC type)
 Frequency: 1 MHz;
 Ambient temperature: 25°C 77°F

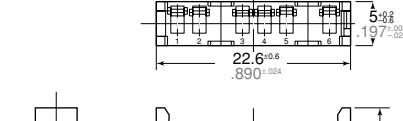


ACCESSORY

Socket

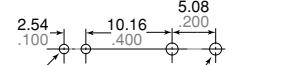


PA1a-PS

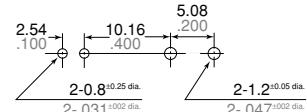


PA1a-PS-H

PC board pattern
(BOTTOM VIEW)
Standard type



Self clinching type



Tolerance: ±0.1 ±.004

mm inch